



### **APT200GN60B2G Information**



For Reference Only

Part Number APT200GN60B2G

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

**Description** IGBT 600V 283A 682W TO247

Package TO-247-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# **APT200GN60B2G Specifications**

Manufacturer Part Number	APT200GN60B2G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3
Series	-
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	600V
Current - Collector (Ic) (Max)	283A
Current - Collector Pulsed (Icm)	600A
Vce(on) (Max) @ Vge, Ic	1.85V @ 15V, 200A
Power - Max	682W
Switching Energy	13mJ (on), 11mJ (off)
Input Type	Standard
Gate Charge	1180nC
Td (on/off) @ 25°C	50ns/560ns
Test Condition	400V, 200A, 1 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3
Supplier Device Package	-
	Report errors?

### **APT200GN60B2G Guarantees**



### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

### **APT200GN60B2G Payment Methods**



















## **APT200GN60B2G Shipping Methods**













If you have any question about APT200GN60B2G, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com